



High-Current Switching Applications

Applications

 DC-DC converters, motor drivers, relay drivers, lamp drivers.

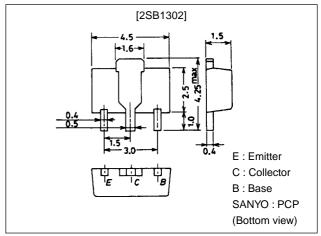
Features

- · Adoption of FBET, MBIT processes.
- · Low collector-to-emitter saturation voltage.
- · Large current capacity.
- · Fast switching speed.
- · Very small size making it easy to provide highdensity, small-sized hybrid ICs.

Package Dimensions

unit:mm

2038



Specifications

Absolute Maximum Ratings at Ta = 25°C

| Parameter | Symbol | Conditions | Ratings | Unit |
|------------------------------|------------------|---|-------------|------|
| Collector-to-Base Voltage | V _{CBO} | | -25 | V |
| Collector-to-Emitter Voltage | VCEO | | -20 | V |
| Emitter-to-Base Voltage | VEBO | | -5 | V |
| Collector Current | Ic | | -5 | А |
| Collector Current (Pulse) | I _{CP} | | -8 | Α |
| Collector Dissipation | PC | Mounted on ceramic board (250mm²×0.8mm) | 1.3 | W |
| Junction Temperature | Tj | | 150 | °C |
| Storage Temperature | Tstg | | -55 to +150 | °C |

Electrical Characteristics at Ta = 25°C

| Parameter | Symbol | Conditions | Ratings | | | Unit |
|--------------------------|-------------------|--|---------|-----|------|------|
| | Symbol | | min | typ | max | Oill |
| Collector Cutoff Current | ICBO | V _{CB} =-20V, I _E =0 | | | -500 | nA |
| Emitter Cutoff Current | I _{EBO} | V _{EB} =-4V, I _C =0 | | | -500 | nA |
| DC Current Gain | h _{FE} 1 | V _{CE} =-2V, I _C =-500mA | 100* | | 400* | |
| | h _{FE} 2 | V _{CE} =-2V, I _C =-4A | 60 | | | |
| Gain-Bandwidth Product | f _T | V _{CE} =-5V, I _C =-200mA | | 320 | | MHz |
| Output Capacitance | C _{ob} | V _{CB} =-10V, f=1MHz | | 60 | | pF |

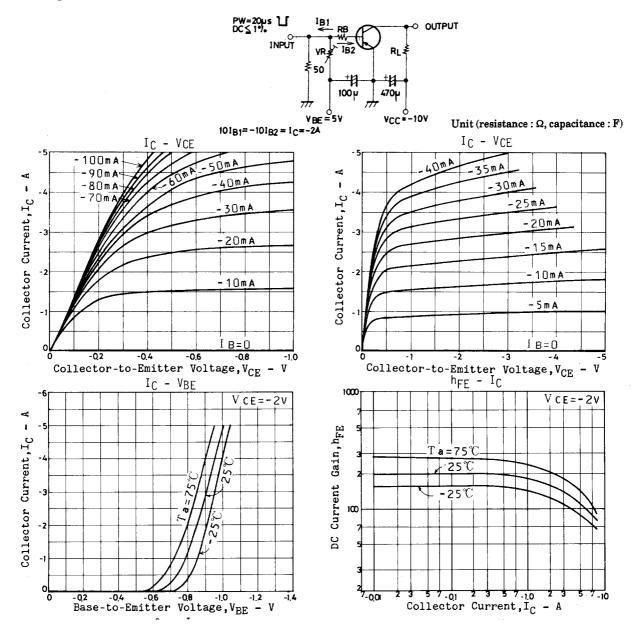
*: The 2SB1302 is classified by 500mA h_{FE} as follows: $100 \,$ R $200 \,$ 140 S $280 \,$ 200 T $40 \,$

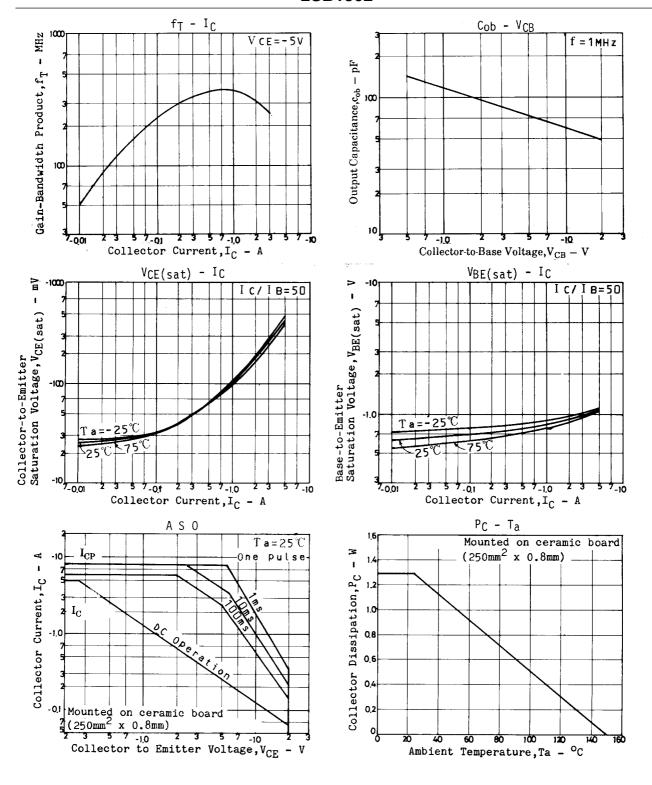
Marking: BJ h_{FE} rank: R, S, T

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| Parameter | Symbol | Conditions | Ratings | | | Unit |
|---|----------------------|--|---------|------|------|--------|
| | | | min | typ | max | O IIII |
| Collector-to-Emitter Saturation Voltage | VCE(sat) | I _C =-3A, I _B =-60mA | | -250 | -500 | mV |
| Base-to-Emitter Saturation Voltage | V _{BE(sat)} | I _C =-3A, I _B =-60mA | | -1.0 | -1.3 | V |
| Collector-to-Base Breakdown Voltage | V(BR)CBO | I _C =-10μA, I _E =0 | -25 | | | V |
| Collector-to-Emitter Breakdown Voltage | V(BR)CEO | I _C =-1mA, R _{BE} =∞ | -20 | | | V |
| Emitter-to-Base Breakdown Voltage | V(BR)EBO | I _E =-10μA, I _C =0 | -5 | | | V |
| Turn-ON Time | ton | See specified test circuit. | | 40 | | ns |
| Storage Time | t _{stg} | See specified test circuit. | | 200 | | ns |
| Fall Time | t _f | See specified test circuit. | | 10 | | ns |

Switching Time Test Circuit





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